



**THE DATASHEET OF  
249NQ150-1**



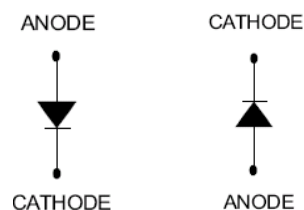
## 249NQ135/R-1 249NQ150/R-1 SCHOTTKY RECTIFIER

### Applications:

- Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

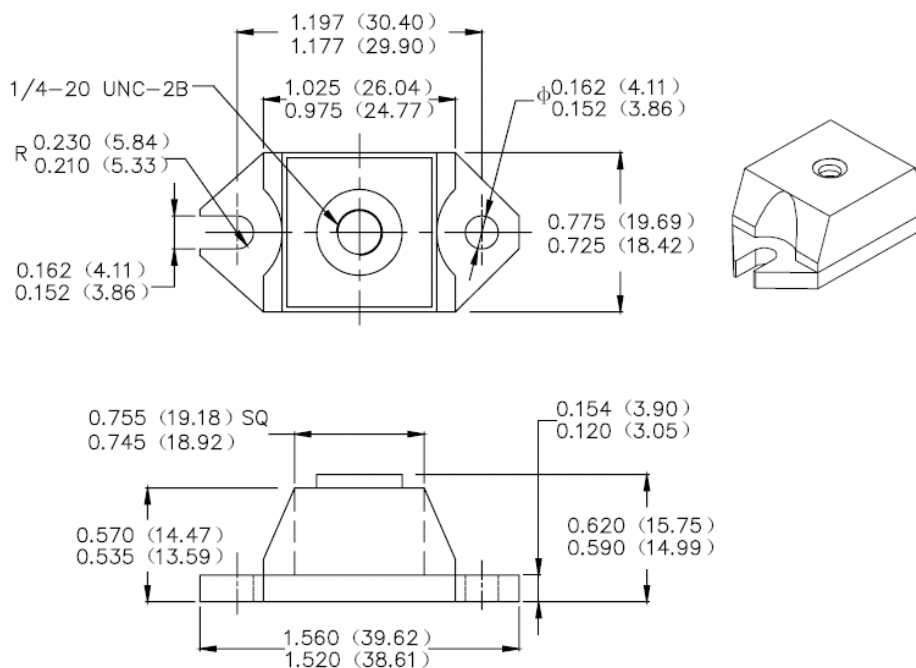
### Features:

- 175°C T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



**249NQ135-1**      **249NQ135R-1**

### Mechanical Dimensions: In Inches / mm



### PRM1-1(HALF PAK Module)

#### MARKING, MOLDING RESIN

Marking for 249NQ135/R-1, 1<sup>st</sup> row SS YYWWL, 2<sup>nd</sup> row 249NQ135-1/249NQ135R-1

Where YY is the manufacture year

WW is the manufacture week code

L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	135	249NQ135/R-1
			150	249NQ150/R-1
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 117^\circ\text{C}$ , rectangular wave form	240	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	$I_{FSM}$	8.3 ms, half Sine pulse	2760	A

**Electrical Characteristics:**

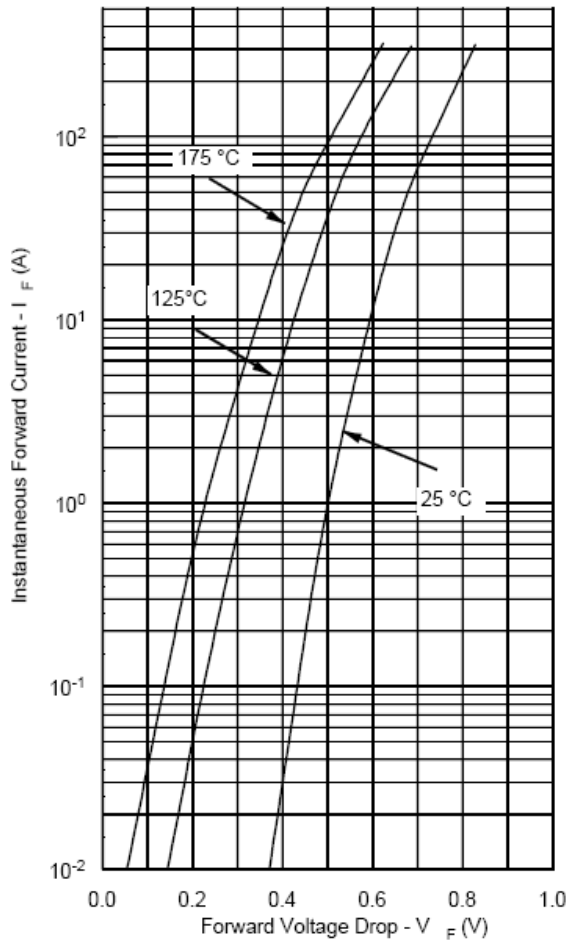
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	$V_{F1}$	@ 240A, Pulse, $T_J = 25^\circ\text{C}$ @ 480A, Pulse, $T_J = 25^\circ\text{C}$	1.07 1.27	V
	$V_{F2}$	@ 240A, Pulse, $T_J = 125^\circ\text{C}$ @ 480A, Pulse, $T_J = 125^\circ\text{C}$	0.74 0.86	V
Max. Reverse Current (per leg) *	$I_{R1}$	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	6	mA
	$I_{R2}$	@ $V_R = \text{rated } V_R$ $T_J = 125^\circ\text{C}$	85	mA
Max. Junction Capacitance (per leg)	$C_T$	@ $V_R = 5\text{V}$ , $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	6000	pF
Typical Series Inductance (per leg)	$L_S$	Measured lead to lead 5 mm from package body	5.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ $\mu\text{s}$

- Pulse Width < 300 $\mu\text{s}$ , Duty Cycle <2%

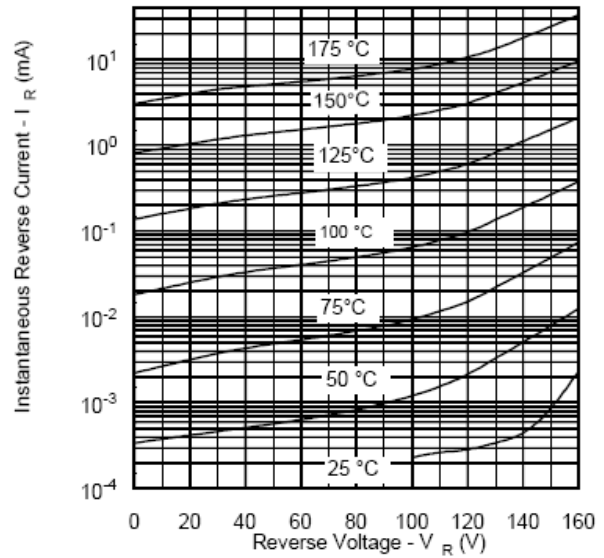
**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +175	$^\circ\text{C}$
Max. Storage Temperature	$T_{stg}$	-	-55 to +175	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.20	$^\circ\text{C/W}$
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.15	$^\circ\text{C/W}$
Mounting Torque	$T_M$	Non-lubricated threads	Mounting Torque	23(min) 29(max)
			Terminal Torque	35(min) 46(max)
Approximate Weight	wt	-	25.6	g
Case Style	PRM1-1			

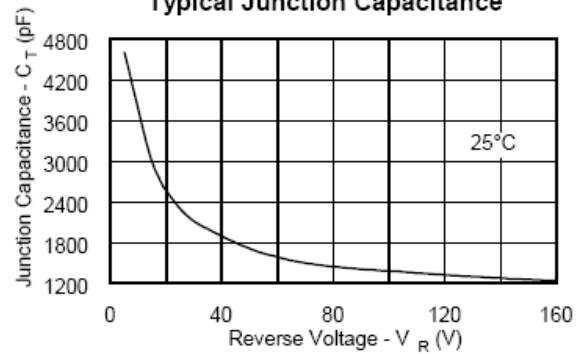
**Typical Forward Characteristics**



**Typical Reverse Characteristics**



**Typical Junction Capacitance**





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